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Hansen, Mikkel Fougt; Rizzi, Giovanni

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# Exchange-biased AMR bridges for magnetic field sensing and biosensing

Mikkel Fougt Hansen<sup>1</sup> and Giovanni Rizzi<sup>1</sup> <sup>1</sup>Department of Micro- and Nanotechnology, DTU Nanotech, Building 345B, Technical University of Denmark, DK-2800 Kongens Lyngby, Denmark

We introduce magnetic field sensor bridges that are formed by combinations of stripes of an exchange-pinned magnetic stack displaying anisotropic magnetoresistance. We present a systematic overview on how the stripe geometries can be combined to form sensor bridges with a scalable signal and how these can be tailored towards detection of external magnetic fields and of magnetic beads over or tethered to the sensor surface. Particular attention is given to the case where the beads are magnetized by the sensor self-field due to the bias current passed through the sensor, which is interesting for magnetic bead sensing and where the static and dynamic magnetic bead response can be monitored in the 2nd harmonic sensor response to an oscillating bias current. The recent literature on applications of these sensors for detection of magnetic fields and of the dynamic and static response of magnetic beads in suspension and attached to the sensor surface is reviewed as well as the use of the sensors for magnetic biosensing in volume-and surface-based formats. We illustrate that the sensors can be flexibly designed and applied for a number of sensing applications with sensitive detection of magnetic fields down to the nT range.

Index Terms-Magnetoresistive sensor, planar Hall effect, magnetic field sensor, magnetic biosensor.

#### I. INTRODUCTION

AGNETIC field sensors based on the anisotropic mag-2 netoresistance (AMR) effect have been used for mag-3 netic field sensing since the 90s [1]-[4] and have in the last decade attracted renewed interest. Compared to the pre-5 dominant giant magnetoresistance sensors they offer a lower signal level but they provide advantages of simpler fabrication, 7 flexibility in choice of device shape and resistance and a high signal-to-noise ratio at low frequencies [5]–[7]. Therefore, they 9 are still attractive for several applications and their use for 10 low-field sensing in, e.g., compasses in mobile phones and 11 satellites, is widespread [8]. 12

AMR sensors can be divided into two main classes. In the 13 first class, the sensors are in the form of crosses that share 14 geometry with Hall sensors. In these a current is injected along 15 one direction in the sensor cross and the voltage difference is 16 measured in the orthogonal direction. The voltage output from 17 a sensor cross is given by the off-diagonal elements in the 18 resistivity tensor and they were therefore been termed planar 19 Hall effect (PHE) sensors. PHE sensors generally produce a 20 low signal but have a high signal-to-noise ratio and they can be 21 optimized to detect sub-nT magnetic fields at low frequencies 22 [6], [7]. To realize the full potential of PHE sensors, however, 23 ultra-low-noise readout electronics is required. In the second 24 class, four AMR elements are combined to form a Wheatstone 25 bridge where the current is still injected along one direction 26 and the voltage is measured in the orthogonal direction [1], 27 [2]. Several geometries of these are available [1], where the 28 most widespread commercial sensors are based on the so-29 called barber pole design [4]. 30

Exchange-biased PHE sensor crosses were introduced for detection of magnetic beads in 2004 by Ejsing *et al.* [9] and spawned a renewed interest in AMR sensors, now with a

Corresponding author: M.F. Hansen (email: mikkel.hansen@nanotech.dtu.dk).

focus on magnetic bead detection and magnetic biosensing [9], 34 [10]. To avoid the need for special low-noise amplification 35 electronics and to increase the sensor signal, Henriksen et 36 al. [11] and Oh et al. [12] introduced Wheatstone bridge 37 geometries of the same exchange-biased stack as used for the 38 PHE sensors. These produced the same dependence of the 39 signal on the magnetization orientation as the PHE sensors, 40 i.e., the signal was given by the off-diagonal elements of 41 the resistivity tensor, but a substantial geometrical signal 42 amplification was obtained. To emphasize the strong kindship 43 between PHE sensors and Wheatstone bridge sensors made 44 from the same exchange-biased stack, Henriksen et al. [11] 45 introduced the term 'planar Hall effect bridge' (PHEB) sensors 46 to distinguish these from other AMR bridge sensors, such 47 as barber pole sensors. This term, although the sensors may 48 more correctly be referred to as 'exchange-biased AMR bridge 49 sensors', was used in subsequent work and will also to some 50 extent be used below. The bridge design has enabled users 51 to better exploit the intrinsically high signal-to-noise ratio 52 for AMR sensors and it has further significantly expanded 53 the sensor design space such that the exchange-biased AMR 54 bridge/PHEB design can be tailored to provide optimal signal 55 for given applications. 56

Here, we present an overview of the construction and reported applications of exchange-biased AMR bridge/PHEB sensors tailored for magnetic field sensing with a special focus on magnetic bead sensing in lab-on-a-chip systems for dynamic magnetic susceptibility measurements and for biosensing applications.

#### II. THEORY

In this section, we first describe the structure of the magnetic stacks used for the sensors. Then, we use energy minimization to obtain a single domain description for the magnetic field response of a stripe (Fig. 1a). We introduce the contributions

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to the magnetic field experienced by a stripe, especially in 68 presence of magnetic beads. We will put particular emphasis 69 on the detection of magnetic beads magnetized by the sensor 70 self-field arising from the bias current passed through the 71 sensor. Finally, we illustrate how stripes can be combined to 72 form sensor bridges with different properties and we present 73 expressions for the bridge signals obtained using lock-in 74 detection. In this manuscript, we will generally write magnetic 75 fields in terms of **B**-fields (=  $\mu_0$ **H**) to simplify notation. 76

#### A. Sensor stack 77

The sensors are generally made of a stack with magnet-78 ically active layers (bottom-to-top)  $Ni_{80}Fe_{20}(t_{fm})/Cu(t_{Cu})/$ 79  $Mn_{80}Ir_{20}(t_{afm})$  deposited on an oxidized Silicon substrate. 80 Additional layers include a Ta buffer layer (typical thickness 81 3-15 nm) and a Ta capping layer (typical thickness 3-5 nm). 82 Here, the ferromagnetic (fm) Ni-Fe layer is the active magne-83 toresistive layer and the antiferromagnetic (afm) Mn-Ir layer 84 is used to pin the magnetization of the fm layer along the x-85 direction in Fig. 1a to achieve a unique single domain magnetic 86 state in zero external magnetic field. This pinning direction 87 is defined by applying a magnetic field during the thin film 88 deposition. Typical values are  $t_{\rm fm}$  =10-30 nm,  $t_{\rm afm}$  =10-20 89 and  $t_{\rm Cu}$  =0-1.2 nm, see Table III. The Cu layer has been 90 introduced to weaken the exchange-pinning of the fm layer to 91 increase the response to an external magnetic field [10], [13], 92 [14] and is only used in later studies. In addition to the above 93 bi- or tri-layer stacks, a spin-valve stack has also been used in 94 a few studies, where a Ni-Fe layer is added between the Cu 95 and Mn-Ir layers [10], [12]. 96

#### B. Single domain model for magnetic response 97

The angle  $\theta$  of the magnetization for a single domain stripe 98 (Fig. 1a) with magnetization  $M_{\rm s}$  can be found by minimizing 99 the magnetic energy. In a magnetic field  $B_y$  acting along the 100 y-direction, the magnetic energy density u for a branch of 101 angle  $\alpha$  can be written as 102

$$u/M_{\rm s} = -B_y \sin\theta - B_{\rm ex} \cos\theta - \frac{1}{2}B_{\rm K} \cos^2\theta - \frac{1}{2}B_{\rm sh} \cos^2(\alpha - \theta).$$
(1)

where  $B_{ex}$  is the exchange-pinning field,  $B_{K}$  is the anisotropy 103 field, and  $B_{\rm sh}$  is the shape anisotropy field [15]. The exchange 104 and anisotropy energy contributions are minimal when M 105 is along the x-axis ( $\theta = 0$ ), whereas the shape anisotropy 106 107 contribution is minimal when M is along the length of the stripe ( $\theta = \alpha$  or  $\alpha + \pi$ ). Thus, it is clear that when the shape 108 anisotropy is not negligible, the value of  $\theta$  should be found 109 separately for all possible stripe orientations. For negligible 110 shape anisotropy, Taylor expansion of the derivative of the 111 energy density to first order gives that u is minimized for 112

$$\theta \approx B_y / (B_{\rm ex} + B_{\rm K}).$$
 (2)

Thus, in this case the magnetization rotation  $\theta$  is proportional 113 to  $B_y$  for low magnetic fields. 114

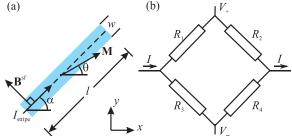


Fig. 1. (a) Illustration of sensor stripe with definitions of geometrical parameters and coordinate system. (b) Wheatstone bridge readout configuration with indication of the positive and negative voltage terminals for the bridge voltage V.

#### C. Contributions to magnetic field

We consider the average total magnetic field  $B_y$  acting on 116 a sensor stripe in the y-direction. The contributions to  $B_y$  can 117 be divided into a contribution  $B_y^{\text{ext}}$  due to a homogeneous 118 external magnetic field  $B_y^{\mathrm{app}}$  applied along the y-direction and 119 a contribution from the magnetic field induced by the bias 120 current passing through the sensor (the self-field),  $B_{y}^{\text{st}}$ , i.e., 121

$$B_y = B_y^{\text{ext}} + B_y^{\text{sf}}.$$
 (3)

When magnetic beads are present over the sensor, they are 122 magnetized by  $B_u^{\text{app}}$  and we can write 123

$$B_y^{\text{ext}} = B_y^{\text{app}}(1 + \beta\chi), \tag{4}$$

where  $\beta$  is a factor accounting for the perturbation of the 124 external magnetic field experienced by the sensor due to the 125 presence of magnetic beads and  $\chi$  is the complex magnetic 126 susceptibility of the beads.  $\beta$  depends on both the amount and 127 distribution of the magnetic beads as well as on the geometry 128 of the sensor. When the beads are magnetized by an external 129 magnetic field, their magnetic dipoles are all aligned along 130 the field. The magnetic field directly under a magnetic bead 131 has a direction opposite to the dipole orientation whereas the 132 magnetic field in front of the dipole is directed along the 133 dipole. This causes both the sign and magnitude of the signal 134 to depend on the detailed arrangement of the beads over the 135 sensor as well as on the height profile of the sensor [16] and 136 in the extreme case of a uniform bead distribution in the half-137 space over the sensor, zero signal is expected [16], [17]. These 138 magnetic bead signal cancellation effects can be mitigated by 139 careful sensor design or by selective functionalization of either 140 the sensor area or the area outside the sensor [16]. In our work, 141 we have not pursued measurements of  $\beta$ , but we maintain  $\beta$ 142 in the description below to keep the description general and 143 consistent. 144

In our application of PHEBs, we magnetize the magnetic 145 beads using the self-field arising from the applied bias current. 146 The self-field circulates around the sensor stripe and thus the 147 magnetic dipole of a magnetic bead changes orientation when 148 it is moved from being over the sensor stripe to outside the 149 sensor stripe. Fig. 2a shows the magnitude of the magnetic 150 field over a sensor stripe at a typical experimental condition. 151 For a stripe with  $\alpha = 0$ , the magnetizing self-field is oriented 152 in the negative y-direction and a magnetic bead placed over the 153

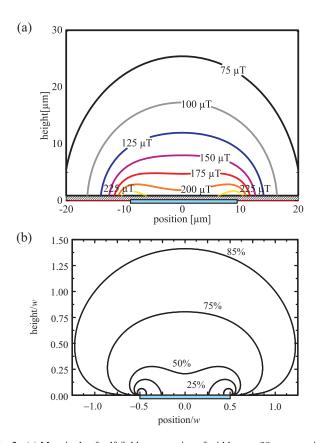


Fig. 2. (a) Magnitude of self-field over a stripe of width  $w = 20 \ \mu m$  carrying a current of 7 mA. Adapted from [18] with permission of AIP publishing. (b) Cummulative signal from homogeneous distribution of magnetic beads in half-space over stripe. Adapted from [19] with permission of AIP publishing. In both graphs, the position of the sensor stripe is indicated by the blue bar.

stripe thus gives rise to a magnetic field acting on the stripe in 154 the positive y-direction. When a magnetic bead is positioned 155 away from the center of the stripe, its dipole moment is 156 aligned with the magnetizing field, with a z-axis component. 157 A detailed analysis of the magnetic field as function of the 158 bead position has revealed that, in this case, the magnetic 159 beads contribute to the signal with the same sign irrespective 160 of their position [19]. Thus, the signal from magnetic beads 161 magnetized by the sensor self-field does not suffer from the 162 cancellation effect that appears for magnetic beads magnetized 163 by a homogeneous magnetic field. The contribution due to the 164 self-field along the y-direction can be written as 165

$$B_y^{\rm st} = I_{\rm stripe}(\gamma_0 + \gamma_1 \chi) \cos \alpha = B^{\rm st} \cos \alpha, \qquad (5)$$

where  $I_{\text{stripe}}$  is the current passed through the stripe,  $\gamma_0$  is 166 a constant accounting for self-bias due to current shunting in 167 other layers than that exhibiting AMR and  $\gamma_1$  is a constant 168 accounting for the volume and distribution of magnetic beads 169 over the sensor [19]. Fig. 2b shows a contour plot of the 170 contribution to the signal from a homogeneous distribution 171 of magnetic beads in a half-space above the sensor stripe. It 172 is observed that about 80-90% of the signal is due to beads 173 within a radius of about 1.3w from the sensor center. The 174 corresponding area of the stripe cross-section is about  $2.7w^2$ 175 [19]. This means, that most of the signal for a single stripe of 176

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length  $l = 280 \ \mu\text{m}$  and  $w = 20 \ \mu\text{m}$  arises from beads in a volume of  $2.7 l w^2 \approx 0.3 \ \text{nL}$ .

#### D. Resistance of sensor construction element

In this section, we present the resistance of the sensor 180 construction element shown in Fig. 1a. The stripe of the 181 magnetic stack has a width w, length l and thickness t. The 182 angle of a positive current passed through the stripe to the 183 x-axis is denoted  $\alpha$  and the stripe is assumed to have a 184 homogeneous magnetization oriented at an angle  $\theta$  to the x-185 axis. Due to anisotropic magnetoresistance, the resistivity of 186 the stripe depends on the relative orientation of the current and 187 the magnetization. The resistivities when these are parallel and 188 perpendicular are denoted  $\rho_{\parallel}$  and  $\rho_{\perp}$ , respectively, and we 189 define  $\Delta \rho \equiv \rho_{\parallel} - \rho_{\perp}$ . Typically,  $\Delta \rho$  is about 2-3% of the 190 average resistivity. Using Ohm's law, it can be shown that the 191 resistance of the single stripe of the magnetic stack shown in 192 Fig. 1a is 193

$$R(\alpha, \theta) = R_0 + \frac{l\Delta\rho}{2wt}\sin(2\theta)\sin(2\alpha), \qquad (6)$$

where  $R_0 = l(\rho_{\parallel} + \rho_{\perp})/(2wt)$  is the stripe resistance when  $\theta = 0$  [11], [20], [21].

Inserting the low-field result for  $\theta$  from Eq. (2) in Eq. (6) 196 yields 197

$$R(\alpha) = R_0 - \sin(2\alpha)S_0B_y \tag{7}$$

with the single stripe low-field sensitivity

$$S_0 \equiv -\frac{l\Delta\rho}{wt(B_{\rm ex} + B_{\rm K})}.$$
(8)

Further inserting the expressions for the total magnetic field  $B_y$  from Eqs. (4)-(5) in Eq. (7) gives 200

$$R(\alpha) = R_0 - \sin(2\alpha) \left( S_0 B_y^{\text{ext}} + S_0 B^{\text{sf}} \cos \alpha \right).$$
(9)

From Eq. (9), it is clear that interesting values of  $\alpha$  are those 201 where  $\sin(2\alpha) = \pm 1$  or  $\cos \alpha = \pm 1$ , i.e.,  $\alpha = p\pi/4$  with 202 p being an integer number. It is also clear that extrema for 203  $\sin(2\alpha)\cos\alpha$  are of interest as they correspond to  $\alpha$ -values 204 that maximize the self-field signal. These are obtained for 205  $\alpha = \arccos(\pm \sqrt{2}/3)$  (maxima) and  $\alpha = -\arccos(\pm \sqrt{2}/3)$ 206 (minima) where  $\sin(2\alpha)\cos\alpha = \pm 0.7698$ . Comparing the re-207 sult for these value to that for  $\alpha = \pi/4$ , where  $\sin(2\alpha) \cos \alpha =$ 208  $1/\sqrt{2} \approx 0.7071$ , the improvement is only about 9%. For 209 simplicity we therefore restrict our considerations below to 210  $\alpha = p\pi/4$ . Table I gives an overview of the signs of the 211 contributions to R due to the external field and the self-field 212 for these values. 213

#### E. Sensor bridge designs

The presented elements can be combined to form the four arms  $R_1 - R_4$  of a Wheatstone bridge as indicated in Fig. 1b, where the resistance of each arm is given by addition of stripes,  $R(\alpha)$ , remembering that  $\alpha$  should be chosen to represent the direction of a positive applied current through the resistor. The output voltage (potential increase in the y-direction) from the bridge is 221

$$V = I \frac{R_2 R_3 - R_1 R_4}{R_1 + R_2 + R_3 + R_4} \approx \frac{1}{2} I (R_3 - R_1), \qquad (10)$$

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TABLE I Overview of the signs of the contributions to the resistance  $R(\alpha) = R_0 + k^{\text{ext}} S_0 B_y^{\text{ext}} + k^{\text{sf}} \frac{1}{\sqrt{2}} S_0 B^{\text{sf}}$  of a stripe due to the external field and the self-field as function of  $\alpha$ , where pdenotes an integer.

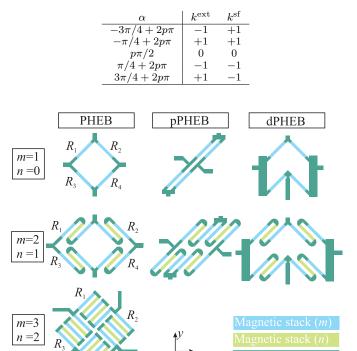


Fig. 3. Illustration of PHEB, pPHEB and dPHEB sensor designs for the indicated values of m (blue stripes with current along  $\pi/4$  in  $R_1$  and  $R_4$ ) and n (green stripes with current along  $-3\pi/4$  in  $R_1$  and  $R_4$ ). In the bottom row is illustrated a compact design of the PHEB sensor with m = 3 and n = 2.

where the latter result is valid when  $R_1 + R_2 \approx R_3 + R_4$ where  $I_{\rm stripe} = I/2$ .

By combining in series multiple resistive elements in a 224 meandering fashion, it is possible to increase the sensor length 225 with a minor increase of the sensor footprint. The space of 226 design parameters is large and we therefore only consider a 227 few combinations of those. Below, we follow and generalize 228 the analysis presented in [21]. The low-field bridge output 229 can easily be calculated for all possible combinations and 230 experimental conditions by use of Eq. (10) with  $R(\alpha)$  given 231 by Eq. (9) or Table I. 232

Figure 3 shows the bridge designs that we have em-233 ployed in our studies. It presents bridges whose arms are 234 a single resistive element or a meander of parallel resistive 235 elements. Let us first consider meandering sensor designs with 236  $R_1 = R_4 = mR(\pi/4) + nR(-3\pi/4)$ , where m and n are 237 non-negative integers, and let us assume that all resistances 238 experience identical values of  $\beta$ ,  $\gamma_0$  and  $\gamma_1$  corresponding to 239 that they all have the same width, are functionalized identically 240 and are exposed to the same sample. Further, we note that 241 often a meander geometry is designed such that n = m - 1242 or n = 0. 243

In the first design, termed PHEB or meander PHEB  $_{245}$  (mPHEB) (Fig. 3), each element in  $R_1$  and  $R_4$  with orientation

 $\alpha$  is matched by a corresponding element in  $R_2$  and  $R_3$  with orientation  $-\alpha$ , i.e., we let  $R_2 = R_3 = mR(-\pi/4) + R(3\pi/4)$  [11], [21]. This design has a high degree of symmetry. The bridge output voltage is 249

$$V^{\text{PHEB}} = I(m+n)S_0 B_y^{\text{ext}} + \frac{1}{\sqrt{2}}I(m-n)S_0 B_y^{\text{sf}}.$$
 (11)

For the external field contribution, the contributions from 250 the two current orientations in each resistor are additive and 251 the signal is proportional to the total length of the meander 252 l(m+n) in each resistor with an observed low-field sensitivity 253  $S_0^{\text{obs}} = (m+n)S_0$ . For the self-field contribution, however, the 254 contributions from the two current orientations are subtractive 255 and the signal is proportional to m - n. Thus, a meander 256 structure does not increase this signal unless one of the current 257 orientations is eliminated (n = 0), e.g., by using a non-258 magnetoresistive conductor [21]. 259

In the second design, termed parallel PHEB (pPHEB) (Fig. 260 3), each element in  $R_1$  and  $R_4$  with orientation  $\alpha$  is matched 261 by a corresponding element in  $R_2$  and  $R_3$  with orientation 262  $\alpha - \pi$ , i.e., we let  $R_2 = R_3 = mR(-3\pi/4) + nR(\pi/4)$ 263 [21]. Inspecting Table I, this design choice conserves the sign 264 of  $k^{\text{ext}}$  but changes the sign of  $k^{\text{sf}}$ , i.e., it eliminates the 265 contribution from a homogeneous external field in the bridge 266 voltage. It can be thought of as an antisymmetric design. The 267 bridge output voltage is 268

$$V^{\text{pPHEB}} = \frac{1}{\sqrt{2}}I(m-n)S_0B_y^{\text{sf}}.$$
 (12)

A third design can be made, which is nominally insensitive 269 to the self-field contribution to the signal such that only 270 the signal due to the external field is detected. Requiring 271 parallel stripes, balanced contributions from the stripes and 272  $k^{\mathrm{ext}} = -1$  for  $R_1$  and  $R_4$  and  $k^{\mathrm{ext}} = +1$  for  $R_2$  and 273  $R_3$ , it observed from Table I that this can be obtained for 274  $R_1 = R_4 = mR(-3\pi/4) + nR(\pi/4)$  and  $R_1 = R_4 =$ 275  $mR(\pi/4) + nR(-3\pi/4)$ . Noting that switching the roles of 276 the current and voltage leads corresponds to the transformation 277  $\alpha \rightarrow -\alpha$  and  $m \rightarrow n$ , we observe that this design can be 278 realized by switching the current and voltage leads of the 279 already presented PHEB design. 280

A final important design, termed differential PHEB 281 (dPHEB) (Fig. 3), relies on differential detection between the 282 top  $(R_1 \text{ and } R_2)$  and bottom  $(R_3 \text{ and } R_4)$  halves of the sensor 283 bridge, where  $R_1 = R_3 = mR(\pi/4) + nR(-3\pi/4)$  and 284  $R_2 = R_4 = mR(-\pi/4) + nR(3\pi/4)$  [20]. Under nominally 285 identical physical conditions (temperature and external mag-286 netic field) and homogeneous amounts of beads on the top and 287 bottom parts, respectively, the bridge voltage from this design 288 is 289

$$V^{\rm dPHEB} = \frac{1}{2}I(m+n)S_0B_y^{\rm app}\Delta\beta\chi + \frac{1}{4\sqrt{2}}I^2(m-n)S_0\Delta\gamma_1\chi$$
(13)

with  $\Delta\beta \equiv \beta^{\text{top}} - \beta^{\text{bottom}}$ ,  $\Delta\gamma_1 \equiv \gamma_1^{\text{top}} - \gamma_1^{\text{bottom}}$  and where we have used  $I_{\text{stripe}} \approx I/2$ . This design can be scaled to more branches, if needed. It produces a signal only due to the magnetic beads and is suited for distinguishing small magnetic bead signals in a background.

#### TABLE II

1<sup>st</sup> and 2<sup>nd</sup> harmonic in-phase and out-of-phase signals calculated for the presented sensor designs. The signal is obtained by multiplying the left column with the column for the relevant sensor design. Adapted from [21] with permission of AIP publishing.

| Lock-in signal                            | PHEB                                | pPHEB                          | dPHEB   |
|---|-------------------------------------|--------------------------------|---|
| $V_1' = (m+n)S_0I_{\rm rms}$              | $B_y^{\mathrm{app}}(1+\beta\chi_0)$ | 0                              | $\frac{1}{2}\Delta\beta B_y^{\mathrm{app}}\chi_0$ |
| $V_1'' = (m+n)S_0I_{\rm rms}$             | 0                                   | 0                              | 0   |
| $V_2' = -\frac{m-n}{4}S_0 I_{\rm rms}^2$  | $\gamma_1\chi^{\prime\prime}$       | $\gamma_1 \chi^{\prime\prime}$ | $\frac{1}{2}\Delta\gamma_1\chi''$                 |
| $V_2'' = -\frac{m-n}{4}S_0 I_{\rm rms}^2$ | $\gamma_0 + \gamma_1 \chi'$         | $\gamma_0 + \gamma_1 \chi'$    | $\frac{1}{2}\Delta\gamma_1\chi'$                  |

### 295 F. Electrical readout and magnetic bead response

In our work, we have almost exclusively used lock-in 296 detection to read out the sensor response. To do this, an 297 alternating current  $I(t) = \sqrt{2}I_{\rm rms}\cos(\omega t)$  is applied and 298 either the 1st or 2nd harmonic lock-in signal is detected. 299 To simplify the description, we only consider dc external 300 magnetic fields below. The magnetic moment response of a 301 magnetic bead to a magnetic field  $H(t) = H_{dc} + H_{ac} \cos(\omega t)$ 302 is 303

$$m(t) = V_{\text{bead}}[H_{\text{dc}}\chi_0 + H_{\text{ac}}|\chi|\cos(\omega t - \phi)], \qquad (14)$$

where  $\chi_0$  is the dc magnetic susceptibility,  $|\chi|$  is the magnitude of the frequency-dependent complex magnetic susceptibility and  $\phi$  is the phase lag of the response with respect to the excitation. Using the cosine relations, this can also be written in terms of the in-phase and out-of-phase components of the magnetic susceptibility  $\chi = \chi' - i\chi'' = |\chi|(\cos \phi - i \sin \phi)$  as

$$m(t) = V_{\text{bead}}[H_{\text{dc}}\chi_0 + H_{\text{ac}}(\chi'\cos(\omega t) + \chi''\sin(\omega t))].$$
(15)

To include the complex susceptibility in the description of the self-field contribution to the signal, we can therefore make the substitution  $\gamma_1 I_{\rm rms} \cos(\omega t) \chi \rightarrow \gamma_1 I_{\rm rms} [\chi' \cos(\omega t) + \chi'' \sin(\omega t)]$  in the expressions for the bridge voltage.

The in-phase and out-of-phase components of the  $n^{\text{th}}$ harmonic signal from the lock-in amplifier can be calculated as

$$V'_{n} = \frac{\sqrt{2}}{2\pi} \int_{-\pi}^{\pi} \cos(n\omega t) V(\omega t) \mathrm{d}(\omega t)$$
(16)

$$V_n'' = \frac{\sqrt{2}}{2\pi} \int_{-\pi}^{\pi} \sin(n\omega t) V(\omega t) \mathrm{d}(\omega t).$$
(17)

The values of  $V'_n$  and  $V''_n$  correspond to the coefficients in a Fourier series representation of V(t) divided by  $\sqrt{2}$ . The results for the presented mPHEB, pPHEB and dPHEB sensors are given in Table II.

Note that with the above definition of the bridge voltage V321 as the potential *increase* in the y-direction,  $V'_1$  has a negative 322 slope vs. applied field as  $S_0$  is defined to be negative in Eq. (8). 323 In studies of the field sensitivity, it has often been convenient 324 to define V as the potential drop in the y-direction (= -V)325 to obtain a positive slope of the signal vs. field response. In 326 studies focusing on magnetic bead detection, the definition of 327 V as the potential *increase* in the y-direction has typically 328 been used as the introduction of magnetic nanobeads in this 329 case causes a positive change in  $V_2$  (cf. Table II with  $S_0 < 0$ ). 330

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In this work, we will consider magnetic beads with a remanent magnetic moment that may relax in a liquid via a physical rotation (Brownian relaxation). This magnetic relaxation process can generally be described by the Debye model [22] 335

$$\chi = \chi' - i\chi'' = \frac{\chi_0 - \chi_\infty}{1 + if/f_B} + \chi_\infty,$$
 (18)

where  $\chi_{\infty}$  is the susceptibility at infinite frequency and  $f_{\rm B}$  is the Brownian relaxation frequency given by

$$f_{\rm B} = \frac{k_{\rm B}T}{\pi^2 \eta d_h^3}.$$
(19)

Here,  $k_{\rm B}T$  is the thermal energy,  $\eta$  is the viscosity of the liquid 338 in which the beads are suspended and  $d_h$  is the hydrodynamic 339 diameter of the beads. A distribution of relaxation times can 340 be accounted for using the empirical Cole-Cole model [23] or 341 by integrating over the size distribution [18]. A measurement 342 of the magnetic susceptibility vs. frequency will show  $\chi' \approx \chi_0$ 343 and  $\chi'' \approx 0$  at  $f \ll f_{\rm B}$  and  $\chi' \approx \chi_{\infty} \ll \chi_0$  and  $\chi'' \approx 0$  at  $f \gg f_{\rm B}$ . The  $\chi''$  data will show a peak at  $f = f_{\rm B}$ , which also 344 345 corresponds to the inflection point in the  $\chi'$  data. 346

#### III. EXPERIMENTAL SETUP

To enable experiments on sensors integrated in a microflu-348 idic channel with minimum handling of a chip, we developed 349 a 'click-on' system providing up to 20 electrical contacts via 350 springloaded pins as well as defining a fluidic channel over 351 the sensors (Fig. 4) [24], [25]. The chip with dimensions 352 of 4.7 mm×7.5 mm was placed in a well in an Al block 353 onto which the top shown in Fig. 4a was placed and locked 354 with two screws. The top provided the electrical contact 355 between the contact pads on the chip and a printed circuit 356 board on the other side containing connectors. The top also 357 contained an inlet and an outlet connected to vertical through-358 holes at each end of the fluidic channel over the chip. The 359 channel outline (1 mm $\times$ 5 mm) was defined in a gasket cast in 360 polydimethylsiloxane (PDMS). The channel height was either 361 1 mm or 0.1 mm. The Al well in which the chip was placed 362 was connected to a Cu bottom onto which a Pt thermometer 363 was mounted. The base of the Cu bottom was placed on 364 a Peltier element providing the heating or cooling of the 365 system. The other side of the Peltier element interfaced with 366 a CPU liquid cooler. The temperature of the Cu bottom was 367 controlled using an LFI-3751 temperature controller (Wave-368 length Electronics, Inc, MT, USA). The temperature of the 369 control thermometer was stable within 0.1°C and the setup 370 covered a range of temperatures between 10°C and 80°C. The 371 temperature setpoint and ramping could be software controlled 372 in LabView. In addition to the temperature control, either an 373 electromagnet with an iron core ( $\pm 40$  mT field range) or a 374 Helmholtz coil (±11 mT field range) could be mounted such 375 that measurements could be performed as function of field and 376 temperature. The mounting of a chip took less than 1 min with 377 a success rate above 90%. 378

The response of up to five sensors could be measured 379 simultaneously using (typically) Stanford Research Systems 380 SR830 lock-in amplifiers after pre-amplification using SR552 381 pre-amplifiers. The sensors were either biased by a constant 382

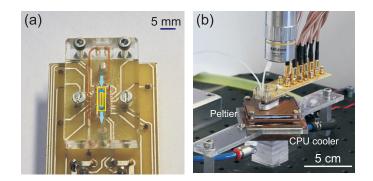


Fig. 4. (a) Picture of top integrating electrical contacts (seen along the sides of the channel), a PDMS gasket defining the outline of the fluid channel (yellow) and inlet/outlet channels (dark blue). The fluid flow is indicated by light blue arrows. (b) The top mounted on a chip in the setup with indication of the Peltier element and the CPU cooler.

current supplied by a Keithley 6221 AC and DC current source
 or by a constant voltage supplied by a high-fidelity audio
 amplifier driven by the voltage output signal from one of the
 lock-in amplifiers.

All measurements presented below were performed in an un-shielded laboratory environment, i.e., with neither magnetic nor electrical shielding of the sensor setup.

#### IV. RESULTS AND DISCUSSION

In this section, we give an overview of the results reported in 391 the literature on exchange-biased AMR bridge sensors. Table 392 III presents the key characteristics of the presented sensors 393 and lists the studies performed using the sensors. In addition 394 to the PHEB, pPHEB and dPHEB sensor designs introduced 395 above, the table also includes a ring-shaped version of the 396 PHEB sensor (ring-PHEB) introduced by Oh et al. [12]. Size-397 limitations on the sensor structures were discussed in [15]. 398 Below, we first give an overview of the results obtained for 399 magnetic field sensing and then we introduce the studies 400 focusing on the detection of magnetic nanobeads. 401

#### 402 A. Magnetic field sensing

390

Fig. 5 shows examples of field sweep measurements on a 403 PHEB sensor of the indicated stack and geometry. The stack 404 with  $t_{\rm fm} = 20$  nm and  $t_{\rm Cu} = 0.6$  nm was identified in Ref. 405 15 as the one with the highest low-field sensitivity of the 406 stacks investigated ( $t_{\rm fm} = 10, 20, 30$  nm and  $t_{\rm Cu} = 0, 0.3, 0.6$ 407 nm). The field sweeps in Fig. 5 are typical for PHEB sensors 408 showing a linear low-field region, a peak in the response at 409  $B_{\rm u} = \pm (B_{\rm ex} + B_{\rm K}/\sqrt{2})$  and subsequently a signal with 410 a decreasing magnitude. The observed low-field sensitivity, 411  $S_0^{\text{obs}}$ , is the slope of the  $V/I_{\text{rms}}$  response at low fields. 412

A number of different sensor geometries and stack compo-413 sitions have been investigated, see Table III. The sensor signal 414 is proportional to the total length  $\Sigma l = (m+n)l$  of a resistor 415 in the bridge for PHEB sensors and inversely proportional to 416 the sensor width w. Therefore, the highest sensitivities have 417 been reported for sensors with high values of  $\Sigma l/w$ . The 418 highest absolute value of the low-field sensitivity reported 419 in each study is listed in Table III. However, the maximum 420

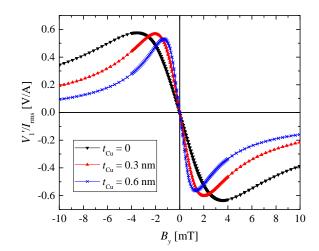


Fig. 5. Field sweeps performed on a PHEB sensor with  $w = 25 \ \mu m$ and  $l = 250 \ \mu m$  of the stack Ta(13 nm)/Ni<sub>80</sub>Fe<sub>20</sub>(20 nm)/Cu( $t_{\rm Cu}$ )/ Mn<sub>80</sub>Ir<sub>20</sub>(10 nm)/ Ta(3 nm) and the indicated values of  $t_{\rm Cu}$ . The sensor was surrounded by magnetic stack with a gap of 3  $\mu m$ . Measurements were performed for a current amplitude of 1 mA. Adapted from [15] with permission of AIP publishing.

achievable signal also depends on the maximum bias current 421 or voltage that can be applied, which may be limited due 422 to sensor self-heating or other constraints introduced by the 423 sensor application [14]. Furthermore, the low-field sensitivity 424 may also be reduced by shape anisotropy of the sensor stripes 425 [15]. Therefore, the sensor dimensions can be only be chosen 426 within certain constraints defined by the sensor stack, the 427 application of the sensors and the surrounding electronics. 428

To enable a comparison of the stack only, Table III also 429 lists the maximum observed low-field sensitivities normalized 430 by  $\Sigma l/w$ . This number provides a measure of  $\Delta \rho/[t(B_{\rm ex} +$ 431  $B_{\rm K}$ )] (see Eq. (8) and Table II). Here, the stack with  $t_{\rm fm} =$ 432 20 nm and  $t_{\rm Cu} = 0.6$  nm, for which the field sweep is shown 433 in Fig. 5, had the highest value and generally the stacks in 434 Table III including a Cu layer showed higher values than their 435 counterparts without Cu. It should be noted that the ring-PHEB 436 sensor design theoretically does not perform as well as the 437 PHEB sensor design with straight conductors [34] but also that 438 the two designs are affected differently by shape anisotropy 439 as discussed in detail in [15]. 440

The lowest magnetic field that can be resolved by the 441 sensors in Table III shows a complex dependence on the 442 intrinsic noise of the sensor, on the bias current applied to 443 the sensor, the frequencies relevant for the sensor use and on 444 the associated detection electronics. Moreover, the practical 445 performance of a sensor depends on the magnitude of the 446 sensor offset and to which extent external parameters, such 447 as temperature and external magnetic field sources, can be 448 kept constant during experiments. Therefore, the sensors with 449 the highest sensitivity in Table III do not necessarily have the 450 highest field resolution. Only very few studies of the noise 451 characteristics of exchange-biased AMR bridges and associ-452 ated equipment exist [36], [37] and the noise characteristics of 453 the sensors and associated equipment for the studies in Table 454 III has not been investigated and is therefore not reported. 455 It should further be noted that the biodetection sensitivity 456

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#### TABLE III

OVERVIEW OF LITERATURE ON PLANAR HALL EFFECT BRIDGE SENSORS OF THE INDICATED PRESENTED DESIGNS (PHEB, PPHEB, DPHEB) AS WELL AS A RING-SHAPED VERSION (RING-PHEB). THE 'STACK' COLUMN GIVES THE THICKNESSES OF THE NI-FE, CU (OPTIONAL) AND MN-IR LAYERS OF THE STACK AND WHEN A PARAMETER IS VARIED, THE INTERVAL OF PARAMETER VALUES IS INDICATED. THE 'DIMENSIONS' COLUMN GIVES THE LENGTH, WIDTH AND NUMBER OF STRIPES FOR THE SENSOR(S). FOR THE RING-PHEB SENSORS, THE NUMBER GIVEN IS THE LARGEST DIAMETER OF A SENSOR RING.  $\rho/t$  is the reported or calculated sheet resistance for the sensor stack.  $|S_0^{obs}|_{max}$  is the largest observed low-field sensitivity normalized by the total length width of one of the resistors of one arm in the bridge. In the 'Studies' column, the key topics of the study are indicated. 'Field' indicates that field sweeps are presented, 'BEADS (vol)' indicates that measurements on Magnetic bead suspensions are performed, 'BEADS (surf)' indicates that surface-based biosensing is performed.

| Ref. | Sensor design      | Stack<br>Ni-Fe/Cu/Mn-Ir<br>[nm] | Dimensions $l/w/(m+n)$ [ $\mu$ m]/[ $\mu$ m]/[-] | $ ho/t$ [ $\Omega$ ] | $ S_0^{ m obs} _{ m max}$<br>[V/(AT)] | $\frac{ S_0^{\rm obs} _{\rm max}}{\Sigma l/w}$ [V/(AT)] | Studies                                    |
|------|--------------------|---------------------------------|--|----------------------|---------------------------------------|---|--|
| 11   | PHEB               | 30/0/20                         | 600/20,30/1-7                                    | 7.9                  | 3790                                  | 18  | Field, meander sensors                     |
| 26   | PHEB               | 30/0/20                         | 280/20/1   | 6.5-6.9              | 807                                   | 58  | Field, effect of temperature and annealing |
| 21   | PHEB, pPHEB, dPHEB | 30/0/20                         | 250/25/1-3                                       | 8.5                  | 555                                   | 19  | Field, beads (vol), geometries             |
| 27   | PHEB               | 10-30/0/10                      | 250/5-25/1                                       | 10-21                | _                                     | _   | Sensor self-heating                        |
| 15   | PHEB, (ring-PHEB)  | 10-30/0-0.6/10                  | 250/25/1   | 10-22                | 720                                   | 72  | Field, geometry, demag effects             |
| 14   | PHEB               | 10-30/0-0.75/10                 | 250/25/1   | 10-22                | 720                                   | 72  | Field, self-field detection of beads       |
| 28   | PHEB               | 30/0/20                         | 280/20/1   | 1710                 | 616                                   | 44  | Beads (vol), cross vs. diamond             |
| 25   | PHEB               | 30/0/20                         | 280/20/1   | 179.5                | 531                                   | 38  | Beads (vol), bead concentration (40 nm)    |
| 29   | PHEB               | 30/0/20                         | 280/20/1   | 179.5                | 581                                   | 42  | Beads (vol), bead size (10-250 nm)         |
| 18   | PHEB               | 30/0/20                         | 280/20/1   | 1710                 | 591                                   | 42  | Beads (vol), time-domain measurements      |
| 30   | PHEB               | 30/0/20                         | 280/20/1   | 10                   | 556                                   | 40  | Beads (vol). Detection of DNA coils        |
| 20   | PHEB, dPHEB        | 30/0/10                         | 250/25/1   | 8.9                  | 300                                   | 30  | Beads (surf), SNP genotyping (washing)     |
| 31   | dPHEB              | 30/0/10                         | 250/25/1   | 178.9                | 300                                   | 30  | Beads (surf), SNP genotyping (T-melting)   |
| 12   | ring-PHEB          | 10/1.2/2/10                     | 300/20/1   | _                    | 95                                    | 8   | Field, multi-ring sensor                   |
|      | -                  | (Spin-valve)                    | 600/20/17  | _                    | 1026                                  | _   |  |
| 32   | ring-PHEB          | 10/0/10                         | 30-150/5,10/1                                    | _                    | 700                                   | 29  | Field, field angle                         |
|      | -                  |                                 | 210/5/7  | _                    | 3300                                  | 25  | -  |
| 33   | ring-PHEB          | 10/0.2/10                       | 210/5/7  | _                    | 6358                                  | 48  | Field, multi-ring sensor                   |
| 32   | ring-PHEB          | 10/0.1/10                       | 24-118/5/5                                       | _                    | 3200                                  | 45  | Field, beads (droplet)                     |

depends not only on the intrinsic sensor noise and fluctuations
of external parameters but also on how the magnetic beads
are placed with respect to the sensor and on the statistical
fluctuations in their number and distribution [38].

#### 461 B. Magnetic bead sensing and biosensing

In this section, we present a brief overview of the studies on 462 magnetic bead detection and magnetic biosensing performed 463 using the presented sensor designs. We will divide the dis-464 cussion in volume-based measurements where the Brownian 465 relaxation response of magnetic nanobeads is measured and 466 surface-based measurements where the signal due to beads 467 tethered to the sensor surface is measured. In Table III, the 468 relevant studies are indicated as 'Beads (vol)' and 'Beads 469 (surf)', respectively. In all studies using the PHEB, pPHEB and 470 dPHEB sensor designs, the magnetic beads were magnetized 471 by the self-field. 472

The practical performance of the PHEB, pPHEB and 473 dPHEB designs for magnetic field detection and magnetic bead 474 detection was investigated in [21], where they were found 475 to exhibit the theoretically anticipated behavior summarized 476 in Table II. The pPHEB and dPHEB designs were found 477 to suppress the signal contribution from an external applied 478 magnetic field by at least a factor of 100, and the dPHEB 479 design was found to suppress the sensor self-bias offset ( $\gamma_0$ 480 contribution) by at least a factor of 50. 481

The effect of self-heating and the limitations on the maximum sensor bias current imposed by a maximum allowable temperature increase due to self-heating were studied in [27] and the implications for the choice of optimal sensor stack and operation conditions for self-field detection were discussed in [14]. 486

#### 1) Volume-based measurements

Initial work focused on demonstrating measurements of the 489 Brownian relaxation of magnetic nanobeads. The use of bridge 490 sensors was initiated in [28], where the additive nature of the 491 self-field response for the PHEB design was presented and 492 on-chip sensor measurements of the magnetic susceptibility 493 of 40 nm and 50 nm magnetic nanobeads were compared to 494 corresponding measurements performed in a commercial ac 495 susceptometer. The study also demonstrated that the sensor 496 measurements, as opposed to ac susceptibility measurements, 497 were sensitive to the sedimentation of magnetic beads as the 498 sensor only probes the sample volume near the sensor surface. 499 The presented bridge design displayed a signal increase by a 500 factor of about six compared to a corresponding cross-shaped 501 sensor and the measurements were found to show essentially 502 the same Brownian relaxation response as obtained in the 503 commercial ac susceptometer. 504

In a subsequent study [25], the response of 40 nm magnetic 505 nanobeads was studied vs. their concentration and for these 506 beads it was found that the signal was proportional to the 507 concentration over almost two decades and that Brownian 508 relaxation frequencies could be extracted reliably for concen-509 trations down to 63  $\mu$ g/mL corresponding to a signal in  $V_2'$  at 510 the Brownian relaxation frequency of 30 nV. Using Table II 511 and the reported values of  $S_0$  obs and  $I_{\rm rms}$ , we estimate that 512 this signal corresponded to an rms magnetic bead field of 15 513 nT and note that the signal was obtained from a volume over 514 the sensor of about 1 nL. Furthermore, it was demonstrated 515

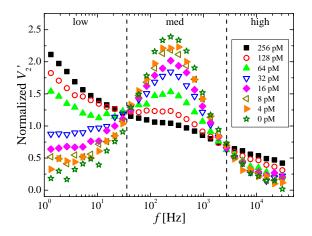


Fig. 6. Measurements of the in-phase sensor response  $V'_2$  for 80 nm functionalized magnetic nanobeads incubated with  $\tilde{1}\mu$ m coils of DNA formed by rolling circle amplification from a *Vibrio Cholerae* target at the indicated concentrations. The  $V'_2$ -response is proportional to the  $\chi''$ -response. The signals from individual beads and beads bound to DNA coils are observed at medium frequencies and low frequencies, respectively. The spectra were normalized with the total signal. Reproduced from [30] with permission of John Wiley and Sons.

that on-chip measurements could be performed between 40 Hz
 and 1 MHz in a matter of minutes.

In a further study, the ability of the sensor platform to 518 perform reliable measurements on beads with different sizes 519 in the range between 40 nm and 250 nm was investigated [29]. 520 In this study, the largest beads with a size of 250 nm were 521 found to provide a signal that drifted and increased with time 522 due to sedimentation of beads on the sensor. Moreover, these 523 beads also showed a hydrodynamic size that was significantly 524 larger than their nominal size, possibly due to agglomeration or 525 interaction with the sensor surface. Further, the signal-to-noise 526 of the Brownian relaxation measurements was used to estimate 527 theoretical limits of detection for bioanalysis and beads with 528 a diameter of 80 nm were identified as optimal. In parallel, 529 a new method for sensor measurements of the relaxation 530 response in the time domain was presented and demonstrated 531 for beads with sizes in the same size range [18]. This method 532 shortened the measurement time from a few minutes to 30 s 533 such that real-time measurements of the relaxation response 534 could be performed. However, the method was also found to 535 have limitations in terms of the bead sizes and in the window 536 of relaxation times that could be resolved. The subsequent 537 work was therefore still based on lock-in measurements in the 538 frequency domain. 539

In a subsequent key study [30], the developed sensor 540 technology was applied for the volume-based detection of 541 DNA amplicons formed via a rolling circle amplification 542 process from a bacterial DNA target from Vibrio Cholerae 543 as well as from a *Bacillus globigii* bacterial spore target. The 544 biomolecular amplification process results in long concatamers 545 of DNA complementary to a padlock probe that recognizes 546 the target. These coil up to form DNA coils with a diameter 547 of about 1  $\mu$ m. The detection of the DNA coils was based 548 on measurements of the significant hydrodynamic size change 549

experienced by the 80 nm magnetic nanobeads when they 550 bind to the DNA coils. The binding causes these beads to 551 contribute with a signal at a substantially lower frequency 552 than the free beads. Figure 5 shows spectra of  $V_2'$  measured 553 on-chip for the indicated concentrations of DNA coils formed 554 from Vibrio Cholerae. Note that these spectra correspond to 555 spectra of the out-of-phase susceptibility,  $\chi''$  (see Table II) 556 and thus display a peak at the Brownian relaxation frequency, 557  $f_{\rm B}$  (Eq. (19)). The spectra could be divided into a regions of 558 medium frequencies dominated by the signal from free beads 559 and low frequencies dominated by the signal from beads bound 560 to DNA coils. Several analysis strategies to address the lack of 561 absolute units of the signal were investigated. The best results 562 were obtained by taking the ratio between the total signal in the 563 low-frequency region to that in the medium-frequency region. 564 In the chip experiments, the sedimentation of beads bound to 565 DNA coils was found to improve their relative signal and thus 566 to improve the sensitivity. The lowest concentration detected 567 of 2 pM compared favorably to the limit of detection obtained 568 using commercial ac susceptometers. 569

#### 2) Surface-based measurements

To perform surface-based measurements of DNA interac-571 tions, selected areas on the sensor surface were functionalized 572 with DNA detection probes. The biotinylated DNA target to 573 be investigated was introduced in the fluid system together 574 with 50 nm streptavidin magnetic beads. Hybridization of 575 the target to the DNA detection probes enabled linking of 576 magnetic beads to the sensor surface. After initial experimental 577 verification of the additivity of the signals from magnetic 578 beads bound to the surface of the different branches of the 579 PHEB design (m = 1, n = 0) [20], subsequent studies of 580 DNA were performed using the dPHEB design with the entire 581 bridge placed centrally in a microfluidic channel where the 582 two top branches of the sensor bridge were functionalized 583 with DNA detection probes and the two bottom branches 584 were left unfunctionalized and thus functioned as a local 585 negative reference. This design was shown to efficiently cancel 586 the sensor offset as well as the signal from magnetic beads 587 in suspension over the sensor such that only beads bound 588 to the top half of the bridge via specific interactions were 589 detected [20]. This enabled real-time measurements of the 590 sensor response due to specific interactions under varving 591 experimental conditions and thereby also during washing steps 592 and temperature changes. 593

The magnetic beads employed in these studies showed 594 a superparamagnetic response. The largest bead signal was 595 found in the  $V_2''$  signal, which is linearly related to the in-596 phase magnetic response,  $\chi'$ . This response was measured 597 at a frequency high enough to ensure fast measurements 598 with low noise and low enough to ensure that most of the 599 magnetic response was in-phase with the self-field. A typical 600 frequency used was f = 167 Hz. In a study of the signal 601 vs. target DNA concentration, we found that a detectable 602 signal with a magnitude of about 15 nV was produced for 603 a concentration down to about 150 pM [20]. The bead signal 604 at this concentration corresponded to an average rms magnetic 605 field of about 3 nT. In subsequent studies, a concentration of 606 about 5 nM was used, which is typical for DNA produced by 607

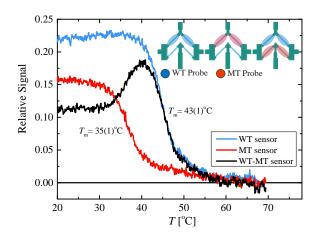


Fig. 7. Measurements of the in-phase sensor response  $V'_2$  for 80 nm functionalized magnetic nanobeads incubated with  $\tilde{1}\mu$ m coils of DNA formed by rolling circle amplification from a *Vibrio Cholerae* target at the indicated concentrations. The  $V'_2$ -response is proportional to the  $\chi''$ -response. The signals from individual beads and beads bound to DNA coils are observed at medium frequencies and low frequencies, respectively. The spectra were normalized with the total signal. Adapted from [31] with permission from Elsevier.

amplification by the polymerase chain reaction (PCR).

The developed sensor platform was used for the detection 609 and genotyping of single nucleotide polymorphisms (SNPs). In 610 [20], we presented real-time measurements of the signal from 611 sensors functionalized with probes targeting wild type (WT) 612 and mutant type (MT) variants of the target during and after 613 a stringent wash. It was demonstrated that the methods could 614 be used for reliable genotyping of two mutation sites of the 615 human beta globin gene. Compared to end-point detection, the 616 real-time analysis enabled robust genotyping even for a probe 617 that gave almost no signal at the end of the stringent washing. 618 Thus, the approach proved to be more flexible in terms of the 619 probe design, where probes for end-point detection often need 620 careful design of their length to produce a detectable signal 621 and robust genotyping. 622

In [31], we further demonstrated that the sensor platform 623 could be used for SNP detection of the same targets via real-624 time measurements of the temperature-melting of the probe-625 target hybrids. In these experiments, sensors functionalized 626 with probes matching the WT and MT target variants were in-627 cubated with the biotinylated target and streptavidin magnetic 628 beads followed by a low-stringency washing step after which 629 the real-time signal was measured as function of increasing 630 temperature. Figure 7 shows the normalized and corrected real-631 time signal for three sensors functionalized as indicated in 632 the inset of Fig. 7 as function of temperature after incubation 633 with a WT target. Both the WT and MT sensors show a clear 634 and nominally flat initial response that decays to zero upon 635 increasing temperature. The melting temperature,  $T_{\rm m}$ , defined 636 as the temperature at which the signal has decreased to half 637 of its initial value, was found to be significantly higher for 638 the matching MT probe than for the mismatching WT probe 639 and the melting temperature difference thus provided a clear 640 genotyping of the sample. The third black curve in the figure 641 shows the response for a sensor bridge functionalized with WT 642

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probes on its top half and MT probes on its bottom half. A clear peak in the corresponding WT-MT signal was observed and the signal matched that obtained by subtraction of the signals from the WT and MT sensors. This demonstrated that the genotyping for this mutation could be obtained using only one sensor bridge.

In addition to the DNA detection studies mentioned above, 649 ring-PHEB sensors have been applied to detect  $1-2 \ \mu L$  of 650 magnetic bead suspensions deposited on the sensor surface 65 [35]. These measurements were carried out using lock-in de-652 tection of the sensor response to an external magnetizing field 653 with a 1 mT ac component and a -3 mT dc component applied 654 at an angle of 20° to the direction of the exchange-pinning 655 field, where the dc field served to increase the sensitivity. The 656 lowest amount of beads detected was estimated to correspond 657 to a magnetic moment of  $4 \times 10^{-16}$  Am<sup>2</sup>. Using their reported 658 sensitivity and signal change, we calculate that the bead signal 659 in this case corresponded to an average magnetic field of about 660 6 nT. 661

## C. Outlook

The presented sensors have demonstrated detection of mag-663 netic fields down to the nT range. For example in Section 664 IV-B2 a 15 nV signal due to surface-bound magnetic beads 665 was resolved [31]. Considering that the thermal voltage noise 666 of this sensor with a resistance of 89  $\Omega$  is  $V_n/\sqrt{\Delta f}$ =667  $\sqrt{4k_{\rm B}TR} \approx 1.2 \text{ nV/Hz}^{1/2}$  and that experiments were per-668 formed at f = 167 Hz with  $\Delta f \approx 1$  Hz, it is likely that the 669 main limiting factor in the presented studies was noise in the 670 electronics used for the readout and/or fluctuations of external 671 parameters such as temperature and the background field in the 672 unshielded laboratory environment where the measurements 673 were performed. Thus, the presented results can likely be 674 further improved by use of more optimal operation conditions. 675 For such an optimization, investigations of the sensor noise 676 characteristics as function of bias current are needed to find 677 the optimum combination of sensor stripe length and bias 678 current to optimize the balance between the sensor signal, 679 the 1/f noise and the thermal noise. At present only few 680 studies of exchange-biased AMR bridges exist and there is a 681 general need for more studies of sensors with different stacks 682 and geometries to establish reliable values of, e.g., the Hooge 683 parameter that characterizes the 1/f noise [36], [37]. 684

As opposed to barberpole AMR sensors, which can be 685 designed to dynamically self-correct for an offset in the sensor 686 response such that absolute field measurements can be per-687 formed [4], the presented sensors suffer from a temperature-688 dependent offset due to a slight unbalance in the bridge. At 689 present, it is yet to be explored to which extent this offset 690 can be nullified and compensated for. Therefore, the present 691 sensors are best used for measurements of field changes, where 692 an offset is a smaller problem. 693

The sensors have proven their ability to detect small amounts of magnetic beads both in volume-based and surfacebased detection formats and that the sensor can be integrated in a flexible lab-on-a-chip platform. The presented detection scheme using the sensor self-field allows for detection with

no signal cancellation effects due to the position of the beads 699 with respect to the sensor. The presented scheme allows 700 for comparatively fast measurements in a compact format, 701 which is capable of covering a wide range of frequencies 702 (dc to MHz). The sensor system is flexible and can be inte-703 grated in lab-on-a-chip systems or other systems for dynamic 704 magnetic measurements. Drawbacks of the system are the 705 limited potential to make low-cost disposable systems and 706 that only relative magnetic susceptibility measurements can be 707 performed. However, as demonstrated, the sensor design space 708 is large and highly flexible offering opportunities to tailor the 709 design and operation of sensors to specific application and to 710 include built-in reference structures. 711

#### V. CONCLUSIONS

We have reviewed the theory of operation of exchange-713 biased AMR bridge sensors, also termed planar Hall effect 714 bridge sensors, starting from simple sensor construction ele-715 ments to how these can be combined to form sensors tailored 716 towards magnetic field sensing, sensing of magnetic beads 717 and differential sensing. We have focused on the special 718 application where the sensors are used to detect magnetic 719 beads being magnetized by the sensor self-field arising from 720 the bias current passed through the sensor and we have 721 presented theoretical expressions for the signals that can be 722 measured using lock-in detection. We have introduced the 723 setup integrating electrical contacts and a fluid channel in a 724 simple 'click-on' system. We have reviewed the literature on 725 magnetic field sensing using planar Hall effect bridge sensors 726 and a simple overview of the characteristics and performance 727 of the presented designs was given. We further reviewed 728 the literature on applications of the sensors for magnetic 729 bead measurements and biosensing either in volume-based or 730 surface-based formats and gave an outlook on challenges and 731 opportunities for these sensors. 732

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**Mikkel Fougt Hansen,** born in 1971, obtained his M.Sc. degree in physics from University of Copenhagen in 1995 and his Ph.D. degree in physics in 1998 from the Technical University of Denmark (DTU). This was followed by postdoctoral positions at Uppsala University and at University of California, San Diego. Since 2002 he has been associate professor at DTU Nanotech at DTU. His present research interests include lab-on-a-chip systems, magnetic nanoparticles, magnetic biosensors and applications thereof.



Giovanni Rizzi, born in 1986 in Milano, Italy, received his M.Sc. degree in Engineering Physics in 2010 at Politecnico di Milano and his Ph.D. degree in physics in 2014 from DTU Nanotech at the Technical University of Denmark, where he is currently also working in a postdoctoral position. His research is focused on developing magnetoresistive sensors as a platform for DNA analysis. His present research interests include lab-on-a-chip systems, biosensors and magnetic sensors.